

# NCE N-Channel Enhancement Mode Power MOSFET

## Description

The NCE6890K uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

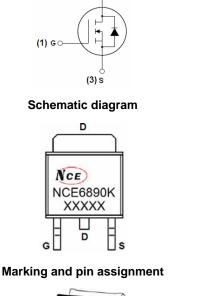
### **General Features**

- $V_{DS} = 68V, I_D = 90A$  $R_{DS(ON)} < 7.5m\Omega @ V_{GS} = 10V$  (Typ:6.5m $\Omega$ )
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### Application

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

## 100% UIS TESTED! 100% ΔVds TESTED!



(2) D



TO-252-2L top view

## **Package Marking and Ordering Information**

Device Marking	Device Device Package		Reel Size	Tape width	Quantity	
NCE6890K	NCE6890K	TO-252-2L	-	-	-	

## Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	68	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	90	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	63	A
Pulsed Drain Current <sup>(Note 1)</sup>	I <sub>DM</sub>	320	A
Maximum Power Dissipation	PD	130	W
Derating factor		0.86	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	380	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>θJc</sub>	1.15	°C/W	]
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## Electrical Characteristics (TC=25°C unless otherwise noted)

V <sub>GS</sub> =0V I <sub>D</sub> =250μA V <sub>DS</sub> =68V,V <sub>GS</sub> =0V			Max	Unit
	68	73	-	V
	-	-	1	μA
V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	3	4	V
V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6.5	7.5	mΩ
V <sub>DS</sub> =10V,I <sub>D</sub> =20A	20	-	-	S
	-	3300	-	PF
	-	450	-	PF
F=1.0MHZ	-	170	-	PF
	-	15	-	nS
V <sub>DD</sub> =30V,I <sub>D</sub> =20A	-	94	-	nS
V <sub>GS</sub> =10V,R <sub>GEN</sub> =6Ω	-	46	-	nS
	-	32	-	nS
N/ 201/1 00A	-	35	-	nC
	-	11	-	nC
V <sub>GS</sub> =10V	-	9	-	nC
	-			
V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
-	-	-	90	А
TJ = 25°C, IF =20A	-	78	-	nS
di/dt = 100A/µs <sup>(Note3)</sup>	-	51	-	nC
Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				y LS+LD)
	$V_{GS}$ =10V,R <sub>GEN</sub> =6Ω $V_{DS}$ =30V,I <sub>D</sub> =20A, $V_{GS}$ =10V $V_{GS}$ =0V,I <sub>S</sub> =20A - TJ = 25°C, IF =20A di/dt = 100A/µs <sup>(Note3)</sup>	$\begin{array}{c c} V_{DS}=30V, V_{GS}=0V, & - & - & - \\ F=1.0MHz & - & - & - \\ V_{DD}=30V, I_{D}=20A & - & - & - \\ V_{GS}=10V, R_{GEN}=6\Omega & - & - & - \\ V_{DS}=30V, I_{D}=20A, & - & - & - \\ V_{GS}=10V & - & - & - & - \\ V_{GS}=10V & - & - & - & - \\ V_{GS}=0V, I_{S}=20A & - & - & - \\ TJ=25^{\circ}C, IF=20A & - & - & - \\ di/dt=100A/\mu s^{(Note3)} & - & - & - \\ \end{array}$	$\begin{array}{c ccccc} V_{DS}=30V,V_{GS}=0V, & - & 450 \\ \hline F=1.0MHz & - & 170 \\ \hline \\ V_{DD}=30V,I_{D}=20A & - & 94 \\ V_{GS}=10V,R_{GEN}=6\Omega & - & 46 \\ \hline \\ - & 322 \\ \hline \\ V_{DS}=30V,I_{D}=20A, & - & 46 \\ \hline \\ - & 322 \\ \hline \\ V_{GS}=10V & - & 35 \\ \hline \\ V_{GS}=10V & - & 9 \\ \hline \\ \hline \\ V_{GS}=0V,I_{S}=20A & - & - \\ \hline \\ TJ = 25^{\circ}C, IF = 20A & - & 78 \\ di/dt = 100A/\mu s^{(Note3)} & - & 51 \\ \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

#### Notes:

**1.** Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

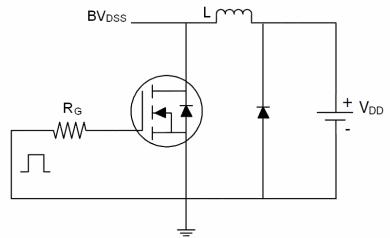
**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

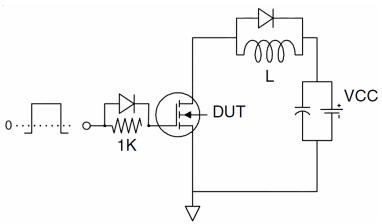
5. EAS condition:Tj=25  $^\circ\!\mathrm{C}$  ,V\_DD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$ 



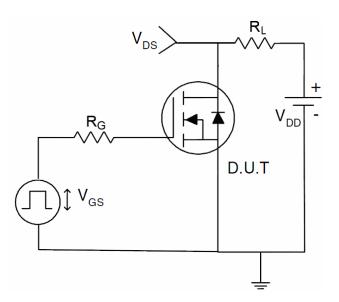
# Test Circuit 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

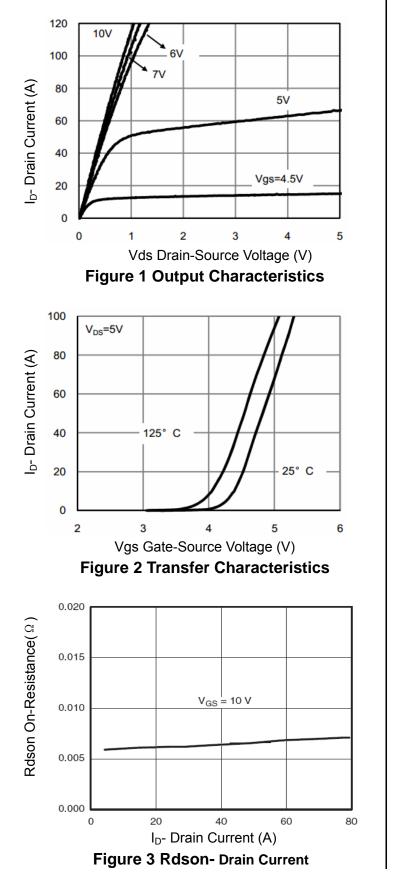


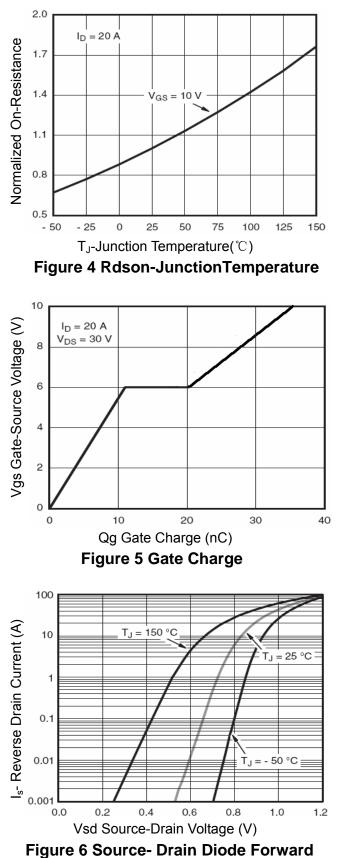
## 3) Switch Time Test Circuit



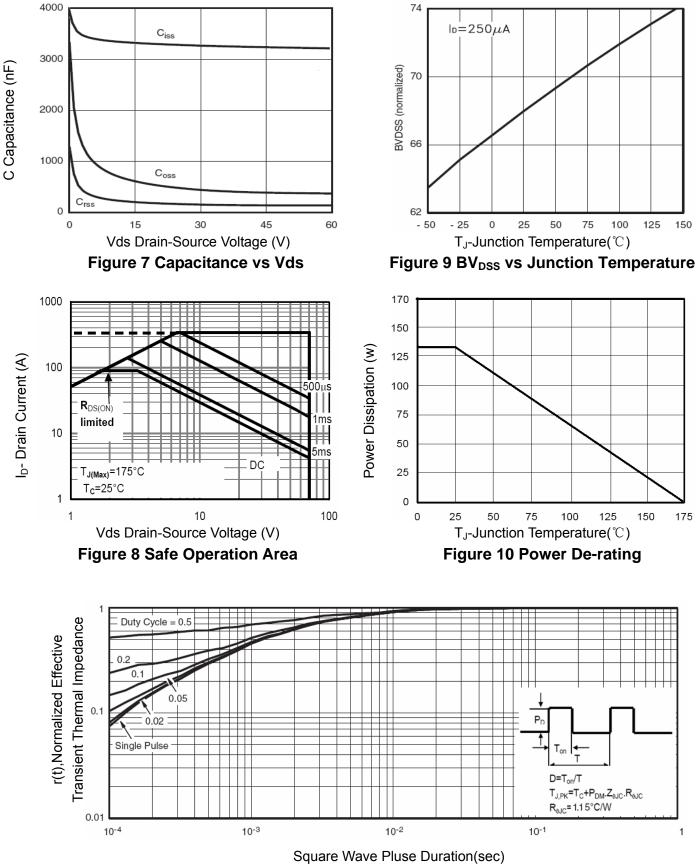


## **Typical Electrical and Thermal Characteristics (Curves)**





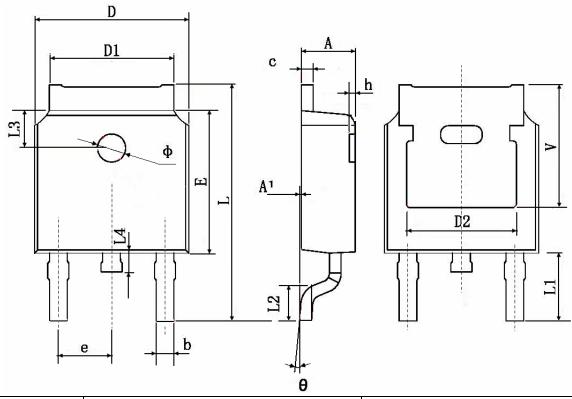








# **TO-252 Package Information**



Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



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